

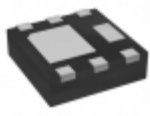



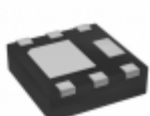
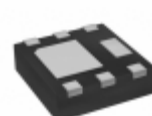

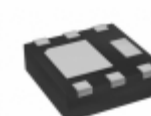
	<b>DMP1011UCB9-7</b>	
	<b>Hersteller-Teilenummer:</b>	DMP1011UCB9-7
	<b>Hersteller / Marke:</b>	Diodes Incorporated
	<b>Teil der Beschreibung:</b>	MOSFET P-CH 8V 10A U-WLB1515-9
	<b>Datenblätter:</b>	 <a href="#">DMP1011UCB9-7.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 50901 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	DMP1011UCB9-7
Hersteller	Diodes Incorporated
Beschreibung	MOSFET P-CH 8V 10A U-WLB1515-9
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	50901 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	9-UFBGA, WLBGA
Supplier Device-Gehäuse	U-WLB1515-9
Verlustleistung (max)	890mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10A (Ta)
Rds On (Max) @ Id, Vgs	10 mOhm @ 2A, 4.5V
VGS (th) (Max) @ Id	1.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	10.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	1060pF @ 4V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs (Max)	-6V
Verpackung	Tape & Reel (TR)



DMP1011UCB9-7 ist neu im Original, Suche DMP1011UCB9-7 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMP1011UCB9-7 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMP1011UCB9-7: Info@Y-IC.com

Sie können auch interessiert sein:

 <b>DMP1012UFDF-13</b> Diodes Incorporated MOSFET BVDSS: 8V 24V U-DFN2020-6	 <b>DMP1012UCB9</b> Diodes Incorporated DMP1012UCB9 DIODES	 <b>DMP1011LFV-13</b> Diodes Incorporated MOSFET P-CH 12V 19A POWERDI3333	 <b>DMP1011LFV-7</b> Diodes Incorporated MOSFET P-CH 12V 19A POWERDI3333
 <b>DMP1009UFDF-13</b> Diodes Incorporated MOSFET P-CH 12V 15A UDFN2020-6	 <b>DMP1012UFDF-7</b> Diodes Incorporated MOSFET BVDSS: 8V 24V U-DFN2020-6	 <b>DMP1012UCB9-7</b> Diodes Incorporated MOSFET P-CH 8V 10A	 <b>DMP1009UFDF-7</b> Diodes Incorporated MOSFET P-CH 12V 15A UDFN2020-6

heiße Teile

Mehr

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|--|---|---|---|---|
|  DMP1005UFDF    |  DMP1009UFDF   |  DMP1012UCB9     |  DMP1012UCB9-7 |  DMP1012UFDF   |
|  DMP1018UCB9    |  DMP1018UCB9-7 |  DMP1022UFDE     |  DMP1022UFDF   |  DMP1045U-7    |
|  DMP1045U-7-F   |  DMP1045UQ     |  DMP1046UFDB     |  DMP1055UFDB-7 |  DMP1055USW-7  |
|  DMP1080UCB4    |  DMP1081UCB4   |  DMP1096UCB4     |  DMP1096UCB4-7 |  DMP10H400SE   |
|  DMP10H400SE-13 |  DMP10H400SEQ  |  DMP10H400SEQ-13 |  DMP10H400SK3  |  DMP10H4D2S    |
|  DMP10H4D2S-7   |  DMP1100UCB4-7 |  DMP1245UFCL     |  DMP1245UFCL-7 |  DMP2002UPS    |
|  DMP2002UPS-13  |  DMP2004DMK-7  |  DMP2004DWK      |  DMP2004DWK-7  |  DMP2004K-7    |
|  DMP2004K-7-F   |  DMP2004KQ-7   |  DMP2004TK       |  DMP2004TK-7   |  DMP2004TK-7-F |
|  DMP2004VK      |  DMP2004VK-7   |  DMP2004WK-7     |  DMP2004WK-7-F |  DMP2006UFG-7  |
|  DMP2008UFG-7   |  DMP200K-7     |  DMP2010UFG-7    |  DMP2012SN-7   |  DMP2022LSS    |

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HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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